

STSJ50NH3LL-VB Datasheet N-Channel 30-V (D-S) MOSFET

PRODUCT SUMMARY				
V _{DS} (V)	$R_{DS(on)}\left(\Omega\right)$	I _D (A)		
30	0.003 at $V_{GS} = 10 \text{ V}$	25		
	0.004 at V _{GS} = 4.5 V	22		

FEATURES

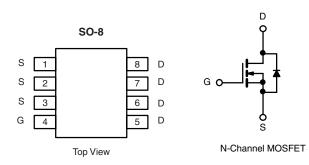
 Halogen-free According to IEC 61249-2-21 Available



 Ultra Low On-Resistance Using High Density Trench Power MOSFET Technology

APPLICATIONS

- · Synchronous Buck Low-Side
 - Notebook
 - Server
 - Workstation
- Synchronous Rectifier-POL



ABSOLUTE MAXIMUM RATINGS	T _A = 25 °C, unle	ss otherwise r	noted		
Parameter		Symbol	10 s	Steady State	Unit
Drain-Source Voltage		V _{DS}	30		V
Gate-Source Voltage		V _{GS}	± 20		V
0 11 0 1/7 150 00/8	T _A = 25 °C	I _D 25 20	17		
Continuous Drain Current (T _J = 150 °C) ^a	T _A = 70 °C		20	13	
Pulsed Drain Current (10 µs Pulse Width)		I _{DM}	70		Α
Continuous Source Current (Diode Conduction) ^a		I _S	2.9	1.3	
Avalanche Current		I _{AS}	50		
	T _A = 25 °C	P _D	3.5	1.6	W
Maximum Power Dissipation ^a	T _A = 70 °C	' D	2.2	1	VV
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 t	o 150	°C

THERMAL RESISTANCE RATINGS						
Parameter	Symbol	Typical	Maximum	Unit		
Manianum lumation to Amelion to	t ≤ 10 s	R _{thJA}	29	35		
Maximum Junction-to-Ambient ^a	Steady State	' 'thJA	67	80	°C/W	
Maximum Junction-to-Foot (Drain)	Steady State	R _{thJF}	13	16		

Notes:

a. Surface Mounted on 1" x 1" FR4 board.

服务热线:400-655-8788

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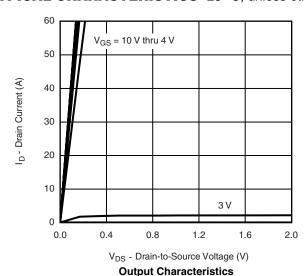
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static							
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = 250 \mu A$	1.0		3.0	V	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			± 100	nA	
Zava Cata Valtaga Drain Current	ı	V _{DS} = 30 V, V _{GS} = 0 V		1			
Zero Gate Voltage Drain Current	IDSS	V _{DS} = 30 V, V _{GS} = 0 V, T _J = 55 °C			5	μΑ	
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \ge 5 \text{ V}, V_{GS} = 10 \text{ V}$	30			Α	
	В	$V_{GS} = 10 \text{ V}, I_D = 25 \text{ A}$		0.003		Ω	
Drain-Source On-State Resistance ^a	R _{DS(on)}	$V_{GS} = 4.5 \text{ V}, I_D = 22 \text{ A}$		0.004			
Forward Transconductance ^a	9 _{fs}	V _{DS} = 15 V, I _D = 25 A		110		S	
Diode Forward Voltage ^a	V_{SD}	I _S = 2.9 A, V _{GS} = 0 V		0.72	1.1	V	
Dynamic ^b							
Input Capacitance	C _{iss}			6500			
Output Capacitance	C _{oss}	$V_{DS} = 15 \text{ V}, V_{GS} = 4.5 \text{ V}, I_D = 20 \text{ A}$		930		pF	
Reverse Transfer Capacitance	C _{rss}			610			
Total Gate Charge	Q_g			45	70		
Gate-Source Charge	Q_{gs}	$V_{DS} = 15 \text{ V}, V_{GS} = 4.5 \text{ V}, I_{D} = 20 \text{ A}$		20		nC	
Gate-Drain Charge	Q_{gd}			16			
Gate Resistance	R_g	f = 1.0 MHz		1.1		Ω	
Turn-On Delay Time	t _{d(on)}			27	40		
Rise Time	t _r	V_{DD} = 15 V, R_L = 15 Ω		21	35		
Turn-Off Delay Time	t _{d(off)}	$I_D \cong 1 \text{ A, V}_{GEN} = 10 \text{ V, R}_g = 6 \Omega$		107	160	ns	
Fall Time	t _f			43	65		
Source-Drain Reverse Recovery Time	t _{rr}	I _F = 2.9 A, dI/dt = 100 A/μs		45	70		

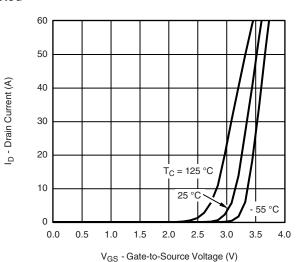
Notes:

- a. Pulse test; pulse width \leq 300 $\mu s,$ duty cycle \leq 2 %.
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

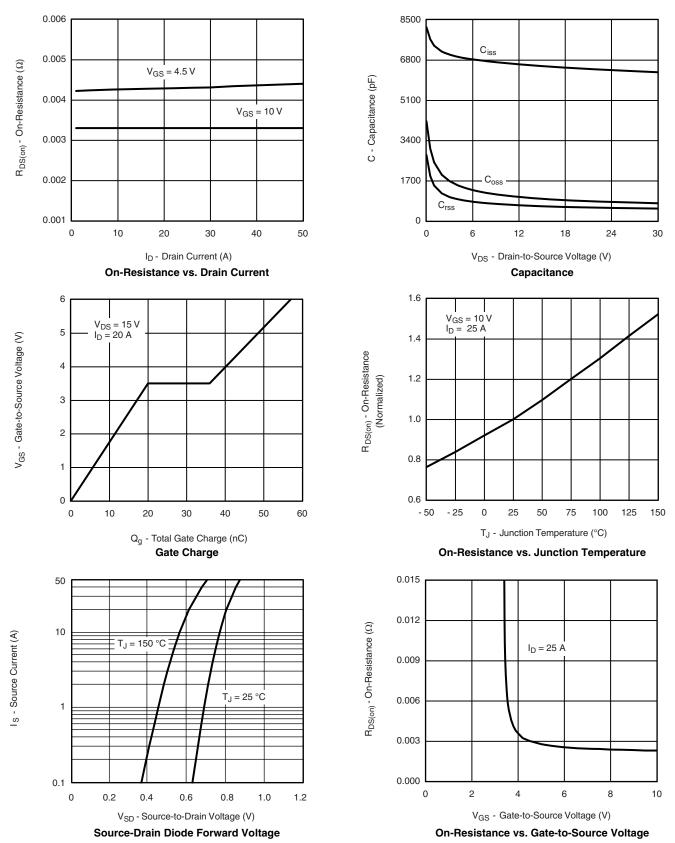




Transfer Characteristics



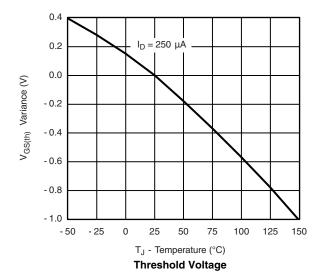
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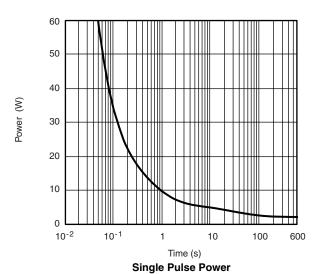


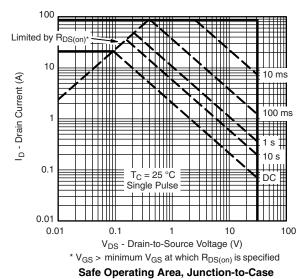
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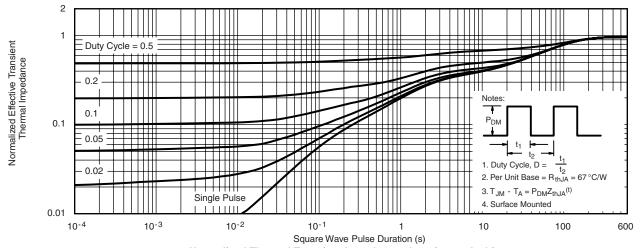




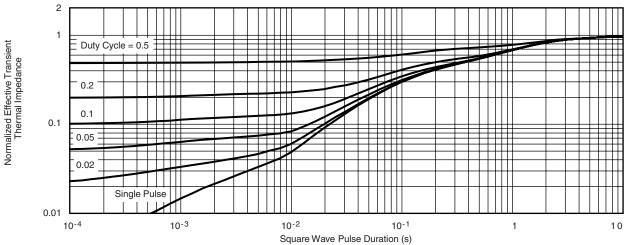




TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Normalized Thermal Transient Impedance, Junction-to-Ambient



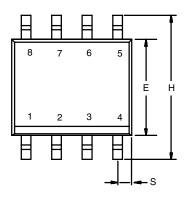
Normalized Thermal Transient Impedance, Junction-to-Foot

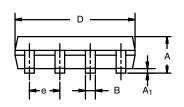
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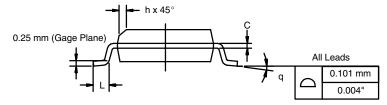
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SOIC (NARROW): 8-LEAD JEDEC Part Number: MS-012





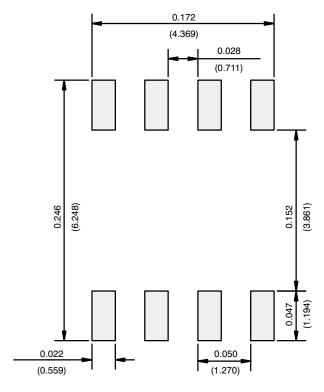


	MILLIM	IETERS	INC	HES		
DIM	Min	Max	Min	Max		
Α	1.35	1.75	0.053	0.069		
A ₁	0.10	0.20	0.004	0.008		
В	0.35	0.51	0.014	0.020		
С	0.19	0.25	0.0075	0.010		
D	4.80	5.00	0.189	0.196		
Е	3.80	4.00	0.150	0.157		
е	1.27	BSC	0.050 BSC			
Н	5.80	6.20	0.228	0.244		
h	0.25	0.50	0.010	0.020		
L	0.50	0.93	0.020	0.037		
q	0°	8°	0°	8°		
S	0.44	0.64	0.018	0.026		
ECN: C-06527-Rev. I, 11-Sep-06						

DWG: 5498



RECOMMENDED MINIMUM PADS FOR SO-8



Recommended Minimum Pads Dimensions in Inches/(mm)



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